In situ spectroelectrochemical ellipsometry using super continuum white laser: Study of the anodization of magnesium alloy

Alexandre Zimmer, Delphine Veys-Renaux, Laurent Broch, Nicolas Stein, Emmanuel Rocca

► To cite this version:

Alexandre Zimmer, Delphine Veys-Renaux, Laurent Broch, Nicolas Stein, Emmanuel Rocca. In situ spectroelectrochemical ellipsometry using super continuum white laser: Study of the anodization of magnesium alloy. *Journal of Vacuum Science & Technology B Microelectronics and Nanometer Structures*, 2019, 37 (6), pp.062911. 10.1116/1.5122320 . hal-02355013

HAL Id: hal-02355013

<https://hal.science/hal-02355013>

Submitted on 8 Nov 2019

HAL is a multi-disciplinary open access archive for the deposit and dissemination of scientific research documents, whether they are published or not. The documents may come from teaching and research institutions in France or abroad, or from public or private research centers.

L'archive ouverte pluridisciplinaire **HAL**, est destinée au dépôt et à la diffusion de documents scientifiques de niveau recherche, publiés ou non, émanant des établissements d'enseignement et de recherche français ou étrangers, des laboratoires publics ou privés.

***In situ* spectroelectrochemical ellipsometry using super continuum white laser: study of the anodization of magnesium alloy**

Running title: in situ study of the anodization of Mg alloy by ellipsometry

Running Authors: Zimmer et al.

Alexandre Zimmer, ^{1,2,a)} Delphine Veys-Renaux, ³ Laurent Broch, ⁴
Nicolas Stein ² and Emmanuel Rocca ³

¹Université de Bourgogne, CNRS, ICB, F-21000 DIJON, FRANCE

²Université de Lorraine, CNRS, IJL, F-57000 METZ, FRANCE

³Université de Lorraine, CNRS, IJL, F-54000 NANCY, FRANCE

⁴Université de Lorraine, LCP-A2MC, F-57000 METZ, FRANCE

^{a)} Electronic mail: alex.zimmer@ellipsometrie.fr

This work shows the interest to use a real time white laser-based ellipsometer to characterize complex electrolyte | electrode interface during electrochemical process in aqueous-based medium. This method is proposed to probe electrochemical interfaces which are usually not suitable to the full extent application of ellipsometry due to great disturbance of the reflected light flux provoked by gas evolution or roughness. *In situ* spectroelectrochemical ellipsometry combining such a visible super continuum fiber laser-band source was not previously reported to the best of the authors' knowledge. The setup was employed to monitor an electrochemical process whose the mechanism was previously incompletely described: the pre-spark anodization regime of plasma electrolytic oxidation process of Mg alloy AZ91D in 3 M KOH electrolyte. Above the anodization voltage of 4 V, the side water oxidation reaction induced light diffusion that reduces reflected light beam intensity. The process is here monitored in an extended

voltage range from 4 to 40 V and in an extended spectral range (495-800 nm). In the presented case, the use of a visible super continuum fiber laser-band source enhanced the signal-to-noise ratio giving access to a more deeper picture of the triplex layer structure during surface repassivation by monitoring the evolution of the outer, inner and interfacial layers.

I. INTRODUCTION

If there is “no-one-solves-all” technique, Spectroscopic Ellipsometry (SE) can undoubtedly participate to efforts to the knowledge of a global picture of the liquid-solid interface¹ as it is the case for passive oxide on metals.²⁻⁹ It can bridge some of the inherent difficulties investigating such oxide growth mechanisms as pointed by MacDonald^{10,11} viz. (i) the alteration during transfer of specimens to further vacuum surface analysis techniques, (ii) the significant cost in time and money of TEM sampling and analyzing, or (iii) the multilayered structure modelling often simplified to a single one.

We have previously monitored, by *in situ* SE, the wet anodization of AZ91D Mg alloy in 3 M KOH medium¹² in order to enhance the understanding of the subsequent sparking regime initiation of the plasma electrolytic oxidation surface treatment,¹³⁻¹⁷ beyond other established literature.¹⁸⁻²⁰ In this former study only the low voltage range i.e. 0-4 V was monitored using a Xe lamp as light source due to the disturbance provoked at the interface by water-oxidation-O₂ bubbles inducing light diffusion and impinging detected flux. A MgO growth at a constant rate of 0.4 nm.V⁻¹ was then highlighted. Beyond 4 V, the study was completed by *ex situ* SE characterizations at three final

voltages (20 V, 30 V and 40 V) leading to propose a global sketch of the insulating layer grown before the apparition of discharges.

This present article brings new detailed data to the aforementioned peculiar anodization mechanism through *in situ* SE study extended up to 40 V, which was made possible thanks to the use of a visible supercontinuum fiber laser-based source increasing the signal-to-noise ratio of the out-coming polarized light. In addition, it was also possible to extend the spectral range from 495 nm to 800 nm instead of the initial spectral range from 495 nm to 700 nm. To the knowledge of the authors, it should be noticed that the ellipsometric setup is quite original, only Miyamoto et al. recently diagnosed microstructure change in plasma facing materials using *in situ* reflectivity measurements based on a super continuum white laser source.²¹

In these conditions, SE confirms the previous general sketch and finely evidences the precipitation of the porous Mg(OH)₂ layer above 4 V and the underlying repassivated MgO layer, from strong variations observed in the breakthrough area (4-15 V) until a smoother morphological evolution up to 40 V.

II. EXPERIMENTAL SETUP AND METHODOLOGY

A. *Materials and sample preparation*

The AZ91D magnesium alloy supplied by Dead Sea Magnesium Ltd. (Israel) was used as substrate material with a chemical composition (wt.%) of Al 9, Zn 0.7, Mn 0.3, Fe < 0.005, Cu < 0.03, Si < 0.1, Mg balance. The samples with a dimension of *ca.* 25 mm x 25 mm x 2 mm were mechanically abraded with successively finer grades of SiC Emery papers up to 1200 and then mirror polished with silica dispersed in water (particle

size 0.1 μm). They were finally rinsed with distilled water and ethanol, then finally dried in air at room temperature.

B. Electrochemical and optical instrumentation

Potentiodynamic measurements (0-40 V) were performed on AZ91D plates with a scan rate of 0.1 V.s^{-1} , in a KOH (3 M) electrolytic solution by using a Modulab HV100 potentiostat (Solartron Analytical). *In situ* SE data were simultaneously acquired with the electrochemical data, using an ellipsometer based on a rotating compensator technology with a homemade coupling flow cell directly mounted on the goniometer. The coupling flow cell (Fig.1), made of PEEK, includes two quartz windows, allowing the reflection of the ellipsometer beam on the working electrode surface (1 cm^2), in a vertical mode. The *ca.* 40-ml flow cell also contains a platinum grid counter-electrode facing the working plate, and a reference electrode of KCl saturated calomel electrode (SCE). The renewal of the electrolyte in the cell is assured with MARPRENE[®] tubes connected to both inlet and outlet via two peristaltic pumps (Model 323E, Watson Marlow). The in-coming beam consists of a supercontinuum fiber laser-based source (Model SM-30-UV, Leukos), and the out-coming beam is split into two perpendicularly polarized waves and simultaneously analyzed by two CCD detectors, which are synchronized, providing final spectrum of averaged ellipsometric angles $\Psi(\lambda)$ and $\Delta(\lambda)$, free of systematic errors. More details can be found elsewhere.²² For each monitoring, $(\Psi(\lambda), \Delta(\lambda))$ are measured in the spectral range 495-800 nm according an integration time of 0.39 s. The optical measurements are performed at angle of incidence of 66°. In addition, the reflected light intensity can be calculated from the ellipsometric signal (see Ref. 5). All the electrochemical data are simultaneously recorded and synchronized with the optical ones

through a dedicated acquisition board. All the experiments are conducted at room temperature (24°C).

FIG. 1. Top-view scheme of the coupling flow cell used for the electrochemical anodization at high voltage in KOH electrolyte in a three electrodes configuration: the working electrode (a), the counter electrode (b) and the reference electrode (c). Visible supercontinuum laser beam enters and leaves the cell through quartz windows (d). Electrolyte circulation enters and leaves the cell through inlet and outlet (e).

III. MODELLING

A. Ellipsometry

SE measures the changes in the polarization state between incident and reflected light on the sample.²³ The measured values are the angles (Ψ , Δ) related to the ratio of the Fresnel amplitude reflection coefficients of the sample by fundamental equation:

$$r_p/r_s = \tan \psi e^{j\Delta} \quad (1)$$

with p- and s-polarized light in the plane of incidence and perpendicular to the plane of incidence, respectively. The parameters of the optical models were determined by minimizing the unweighted mean square error (χ^2) defined as:

$$\chi^2 = \frac{1}{N-1} \sum_{i=1}^N [(\Psi_i^c(\lambda) - \Psi_i^e(\lambda))^2 + (\Delta_i^c(\lambda) - \Delta_i^e(\lambda))^2] \quad (2)$$

where ‘c’ stands for the calculated and ‘e’ for the experimental ellipsometric angles and N the number of experimental couples of data.

B. Optical model

Figure 2 shows the model used to adjust the experimental data from 4 V to 40V. The alloy substrate is covered by a native oxide film consisting of an interfacial layer (thickness $d_{\text{interface}}$) covered by a dense and pure magnesium oxide layer (thickness d_{MgO}). The interfacial layer is composed by mixing a f_{MgO} % MgO compound and $(1-f_{\text{MgO}})$ % AZ91D alloy, where f_{MgO} is the fitted volume fraction of MgO in the interfacial layer. The effective dielectric function of this composite layer, noted $\epsilon_{\text{interface}}$ is modelled using the EMA based on the Bruggeman's model following the second-order equation:

$$0 = f_{\text{MgO}} \frac{\epsilon_{\text{MgO}}(\lambda) - \epsilon_{\text{interface}}(\lambda)}{\epsilon_{\text{MgO}}(\lambda) + 2\epsilon_{\text{interface}}(\lambda)} + (1 - f_{\text{MgO}}) \frac{\epsilon_{\text{AZ91D}}(\lambda) - \epsilon_{\text{interface}}(\lambda)}{\epsilon_{\text{AZ91D}}(\lambda) + 2\epsilon_{\text{interface}}(\lambda)} \quad (2)$$

In the 495-800 nm wavelength range, the dielectric function of periclase $\epsilon_{\text{MgO}}(\lambda)$ was taken from literature data.²⁴ For the substrate, the dielectric function of the AZ91D Mg alloy $\epsilon_{\text{AZ91D}}(\lambda)$ was determined from variable angle spectroscopic ellipsometry measurements using a wavelength point-to-point exact numerical inversion taking into account the surface roughness. See supplementary material 1 at [URL will be inserted by AIP Publishing] for the spectra of its corresponding complex refraction index $N_{\text{AZ91D}}(\lambda) = \sqrt{\epsilon_{\text{AZ91D}}(\lambda)}$. The dense MgO layer is modelled with the aforementioned dielectric function $\epsilon_{\text{MgO}}(\lambda)$. An outer porous layer is implemented of magnesium hydroxide (thickness $d_{\text{Mg(OH)2}}$ and volume fraction of Mg(OH)_2 $f_{\text{Mg(OH)2}}$). This additional outer EMA layer is calculated in a same way as Eq.(2) using $\epsilon_{\text{water}}(\lambda)$ and $\epsilon_{\text{Mg(OH)2}}(\lambda)$.²⁵

The dielectric function of the electrolytic medium was modelled with the dielectric function of water²⁶, $\epsilon_{\text{water}}(\lambda)$ in the 495-800 nm range. $\epsilon_{\text{AZ91D}}(\lambda)$, $\epsilon_{\text{MgO}}(\lambda)$, $\epsilon_{\text{Mg(OH)}_2}(\lambda)$ and $\epsilon_{\text{water}}(\lambda)$ functions are considered as constant with the anodization voltage. Consequently, five variables were fitted, namely $d_{\text{interface}}$, f_{MgO} , d_{MgO} , $d_{\text{Mg(OH)}_2}$, and $f_{\text{Mg(OH)}_2}$.

The calculated angles ($\Psi(\lambda)$, $\Delta(\lambda)$) values well match the experimental ones as proven by the low χ^2 values less than or equal to 1 (Fig.3, second right axis, as discussed thereafter), indicating that the optical model is adequate to describe the structure of the anodized film over the full covered voltage range.

FIG. 2. Optical model used along the anodization of AZ91D alloy in KOH 3 M at 0.1 V.s⁻¹. Fitted variables consist of thicknesses (d) and volume fractions (f). Dielectric functions were all fixed and come from literature (MgO, Mg(OH)₂, electrolyte) or are experimentally predetermined (AZ91D).

IV. RESULTS AND DISCUSSION

A. Preliminary analysis of the reflected light intensity

Figure 3 shows the reflected light intensity (left axis) simultaneously recorded to the potentiodynamic curve (first right axis) obtained for Mg AZ91D alloy in pure 3 M

KOH electrolyte. For the sake of brevity only one wavelength (600 nm) is shown for the optical signal. For applied voltages of up to 4 V current density values of 0.2-0.3 mA.cm⁻² are observed (first passive state), whereas ten times higher ones are noticed when the voltage comes to 15 V (second passive state). The key region is between these two passive states named here as breakthrough. The optical signal is therein disturbed, dropping to 20% but it goes up to a final plateau, with a relative high reflective intensity superior to 50 %. Consequently, concerning the optical data, the signal-to-noise ratio remains high and the overall level of confidence is considered as high enough. As a fit quality criterion, the χ^2 values also depicted in Fig.3 (second right axis) are found low.

FIG. 3. Variation of the reflected intensity of the beam light at 600 nm (open circle symbols, left axis) during the potentiodynamic scan (bold line, first right axis) of the anodization of AZ91D alloy in KOH 3 M at 0.1 V.s⁻¹. Best fitted χ^2 values are given in the second right axis.

B. Analysis of the anodization process

Figure 4 shows the morphological properties determined by ellipsometry. From 0 to 4 V, the previous in situ monitoring experiments¹² have shown that a pure and compact MgO layer linearly increases. Above 4V, this work demonstrates that the film has to be considered as triplex according to the model of the figure 3. Indeed the corresponding the χ^2 values are inferior to 0.5 proving the suitability of the optical interface model.

This is the author's peer reviewed, accepted manuscript. However, the online version of record will be different from this version once it has been copyedited and typeset.

PLEASE CITE THIS ARTICLE AS DOI: 10.1116/1.5122320

FIG. 4. Best fitted variables monitored by SE of (a) external Mg(OH)_2 layer (b) inner MgO layer and (c) interfacial layer. f_{MgO} is fixed in the 0-4 V range (dashed line). The

grayed area corresponds to the voltage range where optical model errors introduced artifacts in the fitted parameters.

From 4 to 7 V, the upper magnesium hydroxide reaches a thickness of *ca.* 300 nm (Fig. 4a, left axis). Its porosity is important as indicated by the f_{MgOH_2} values (Fig. 4a, right axis). In the meantime, under this membrane, both MgO dense and interfacial layer vary significantly. The dense oxide layer sharply grows up to 50 nm at 5.5 V (Fig.4b), meanwhile the interfacial layer decreases abruptly. From 5.5 to 7 V the dense MgO layer in turn dramatically vanishes, before going up again towards a final repassivation. This evolution highlights the partial exposure of the base substrate. The second and final passive state at 7 V consecutive to the breakthrough occurrence consists of a rougher interfacial layer (~25 nm) and a thicker dense oxide layer (~50 nm). The repassivation starts under the outer membrane: a net uptake of dense MgO component in the $\text{Mg}(\text{OH})_2/\text{MgO}/\text{interface}$ is rapidly raised from 7 to 8 V i.e. $\sim 35 \text{ nm.V}^{-1}$ assuming a linear evolution. In addition to the oxide growth, the water oxidation at the interface is still promoted, interfering somewhat with the reflected light beam which intensity passes through a minimum in this area (Fig. 3). From 10 V the second passive state evolves slightly up to 40 V. Concerning the MgO layer, its thickness goes from 55 to 74 nm. By taking into account its effective thickness (See supplementary material 2 at [URL will be inserted by AIP Publishing]) i.e. from 69 to 83 nm, a second wide linear growth regime of 0.7 nm.V^{-1} is highlighted and therefore refining the previous rougher estimation.¹² The $\text{Mg}(\text{OH})_2$ layer is becoming denser (Fig. 4) with a nearly constant effective thickness of 106 nm (See supplementary material 2 at [URL will be inserted by AIP Publishing]). These observations are in good agreement with the hypothesis of anodization mechanism

governed by stress-induced MgO cracking and $\text{Mg}(\text{OH})_2$ precipitation process. These results finely confirm the protective role of the outer layer limiting the dissolution of the underlying MgO layer.

V. CONCLUSIONS

Among other techniques, SE participates as an analytical tool to diagnose solid-liquid interfaces during wet processes and helps understanding the electrochemical processes. Probing such complex electrode/electrolyte interfaces is sometimes turmoil due to side reactions producing gas species impinging the reflected light beam in a manner that data are inoperative or just missing. This article has presented a setup arrangement combining a real time ellipsometer, an electrochemical coupling cell and a super continuum white laser to get a significant increase of the out-coming light in such depreciated monitoring conditions. The proposed setup was applied successfully to monitor the case of the pre-sparking anodization of a piece of magnesium alloy AZ91D by finely revealing the morphological characteristics of its multilayered structure. The consolidation of such *in situ* SE methodology with the use of a white laser is highlighted to be a convenient method for probing liquid processes that are traditionally excluded from the full extent of SE.

ACKNOWLEDGMENTS

Thanks to José Manuel Lopez (Université de Lorraine) for the fabrication of the coupling cell. Ellipsometric data were acquired at the Ellipsometry core facility of LCP-A2MC, Université de Lorraine - <http://lcp-a2mc.univ-lorraine.fr>.

- ¹ K. Hingerl, in *Ellipsom. Nanoscale*, Springer (Losurdo, M., Hingerl, K., Berlin Heidelberg, 2013), pp. 493–527.
- ² T. Ohtsuka and K. Fushimi, *Electrochemistry* **84**, 826 (2016).
- ³ L. Berlouis, D. Mamman, and I. Azpuru, *Surf. Sci.* **408**, 173 (1998).
- ⁴ S. Böhm, R. Greef, H. McMurray, S. Powell, and D. Worsley, *J. Electrochem. Soc.* **147**, 3286 (2000).
- ⁵ N. Stein, G. Bourguignon, L. Raboin, L. Broch, L. Johann, and E. Rocca, *Thin Solid Films* **455–456**, 735 (2004).
- ⁶ Z. Lu and D.D. Macdonald, *Electrochimica Acta* **53**, 7696 (2008).
- ⁷ Y. Chen and A. Erbe, *Surf. Sci.* **607**, 39 (2013).
- ⁸ P. Laha, M. Nazarkin, A. Volkova, M. Simunin, H. Terryn, S. Gavrilov, and J. Ustarroz, *Appl. Phys. Lett.* **106**, 101904 (2015).
- ⁹ Y. Takabatake, Y. Kitagawa, T. Nakanishi, Y. Hasegawa, and K. Fushimi, *J. Electrochem. Soc.* **164**, C349 (2017).
- ¹⁰ D.D. Macdonald, *Russ. J. Electrochem.* **48**, 235 (2012).
- ¹¹ J.D. Sloppy, D.D. Macdonald, and E.C. Dickey, *J. Electrochem. Soc.* **157**, C157 (2010).
- ¹² A. Zimmer, D. Veys-Renaux, L. Broch, N. Stein, and E. Rocca, *J. Electrochem. Soc.* **164**, C1059 (2017).
- ¹³ C. Barchiche, D. Veys-Renaux, and E. Rocca, *Surf. Coat. Technol.* **205**, 4243 (2011).
- ¹⁴ D. Veys-Renaux, E. Rocca, and G. Henrion, *Electrochem. Commun.* **31**, 42 (2013).
- ¹⁵ D. Veys-Renaux, E. Rocca, J. Martin, and G. Henrion, *Electrochimica Acta* **124**, 36 (2014).
- ¹⁶ E. Rocca, D. Veys-Renaux, and K. Guessoum, *J. Electroanal. Chem.* **754**, 125 (2015).
- ¹⁷ D. Veys-Renaux and E. Rocca, *J. Solid State Electrochem.* **19**, 3121 (2015).
- ¹⁸ A. Yerokhin, X. Nie, A. Leyland, A. Matthews, and S. Dowey, *Surf. Coat. Technol.* **122**, 73 (1999).

This is the author's peer reviewed, accepted manuscript. However, the online version of record will be different from this version once it has been copyedited and typeset.

PLEASE CITE THIS ARTICLE AS DOI: 10.1116/1.5122320

- ¹⁹ J. Yahalom and J. Zahavi, *Electrochimica Acta* **16**, 603 (1971).
- ²⁰ S. Ikonopisov, *Electrochimica Acta* **22**, 1077 (1977).
- ²¹ M. Miyamoto, M. Yamamoto, T. Akiyama, N. Yoshida, M. Tokitani, and A. Sagara, *Nucl. Mater. Energy* **9**, 132 (2016).
- ²² L. Broch, N. Stein, A. Zimmer, Y. Battie, and A.E. Naciri, *Thin Solid Films* **571**, 509 (2014).
- ²³ J. Chen and Q. Zhan, in *Handb. Adv. Non-Destr. Eval.*, Springer (Ida N., Meyendorf N., Cham, 2018), pp. 1–29.
- ²⁴ D.M. Roessler and D.R. Huffman, in *Handb. Opt. Constants Solids II*, Academic Press (Palik, E.D., Orlando, Florida, 1991), pp. 919–955.
- ²⁵ A. Pishtshev, S.Z. Karazhanov, and M. Klopov, *Comput. Mater. Sci.* **95**, 693 (2014).
- ²⁶ M.R. Querry, D.M. Wieliczka, and D.J. Segelstein, in *Handb. Opt. Constants Solids II*, Academic Press (Palik, E.D., Orlando, Florida, 1991), pp. 1059–1078.
- ²⁷ S.D. Cramer and B.S. Covino, *Corrosion: Fundamentals, Testing and Protection* (ASM international, 2003).

Figure captions

FIG. 1. Top-view scheme of the coupling flow cell used for the electrochemical anodization at high voltage in KOH electrolyte in a three electrodes configuration: the working electrode (a), the counter electrode (b) and the reference electrode (c). Visible supercontinuum laser beam enters and leaves the cell through quartz windows (d). Electrolyte circulation enters and leaves the cell through inlet and outlet (e).

FIG. 2. Optical model used along the anodization of AZ91D alloy in KOH 3 M at 0.1 V.s⁻¹. Fitted variables consist of thicknesses (d) and volume fractions (f). Dielectric functions were all fixed and come from literature (MgO, Mg(OH)₂, electrolyte) or are experimentally predetermined (AZ91D).

FIG. 3. Variation of the reflected intensity of the beam light at 600 nm (open circle symbols, left axis) during the potentiodynamic scan (bold line, first right axis) of the anodization of AZ91D alloy in KOH 3 M at 0.1 V.s⁻¹. Best fitted χ^2 values are given in the second right axis.

FIG. 4. Best fitted variables monitored by SE of (a) external Mg(OH)₂ layer (b) inner MgO layer and (c) interfacial layer. f_{MgO} is fixed in the 0-4 V range (dashed line). The grayed area corresponds to the voltage range where optical model errors introduced artifacts in the fitted parameters.

This is the author's peer reviewed, accepted manuscript. However, the online version of record will be different from this version once it has been copyedited and typeset.
PLEASE CITE THIS ARTICLE AS DOI: 10.1116/1.5122320

This is the author's peer reviewed, accepted manuscript. However, the online version of record will be different from this version once it has been copyedited and typeset.
PLEASE CITE THIS ARTICLE AS DOI: 10.1116/1.5122320

This is the author's peer reviewed, accepted manuscript. However, the online version of record will be different from this version once it has been copyedited and typeset.

PLEASE CITE THIS ARTICLE AS DOI: 10.1116/1.5122820

Reflective light intensity

@ 600 nm / a.u.

This is the author's peer reviewed, accepted manuscript. However, the online version of record will be different from this version once it has been copyedited and typeset.
PLEASE CITE THIS ARTICLE AS DOI: 10.1116/1.5122320

a

Thickness of $\text{Mg}(\text{OH})_2$ layer / nm

b

This is the author's peer reviewed, accepted manuscript. However, the online version of record will be different from this version once it has been copyedited and typeset.
PLEASE CITE THIS ARTICLE AS DOI: 10.1116/1.5122320

c

Thickness of interfacial layer / nm